High Power Infrared Emitter (850 nm) Version 1.4

SFH 4232



Features:

- IR lightsource with high efficiency
- Low thermal resistance (Max. 9 K/W)
- Centroid wavelength 850 nm
- Superior Corrosion Robustness (see chapter package outlines)
- The product qualification test plan is based on the guidelines of AEC-Q101-REV-C, Stress Test Qualification for Automotive Grade Discrete Semiconductors.
- Package: SMT package

Applications

- Infrared Illumination for cameras
- Surveillance systems
- Machine vision systems

Notes

Depending on the mode of operation, these devices emit highly concentrated non visible infrared light which can be hazardous to the human eye. Products which incorporate these devices have to follow the safety precautions given in IEC 60825-1 and IEC 62471.

Ordering Information

Туре:	Total Radiant Flux	Ordering Code	
	Φ _e [mW]		
	I _F = 1A, t _p = 10 ms		
SFH 4232	530 (≥320)	Q65110A8754	

Note: Measured with integrating sphere.



Maximum Ratings (T_A = 25 °C)

Parameter	Symbol	Values	Unit
Operation and storage temperature range	T _{op} ; T _{stg}	-40 125	°C
Junction temperature	Tj	145	°C
Reverse voltage	V _R	1	V
Forward current	I _F	1000	mA
Surge current $(t_p \le 200 \ \mu s, D = 0)$	I _{FSM}	5	A
Power consumption	P _{tot}	1800	mW
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	V _{ESD}	2	kV
Thermal resistance junction - soldering point	R _{thJS}	9	K / W

Characteristics (T_A = 25 °C)

Parameter	Symbol	Values	Unit
Peak wavelength ($I_F = 1 \text{ A}, t_p = 10 \text{ ms}$)	λ_{peak}	860	nm
Centroid wavelength ($I_F = 1 \text{ A}, t_p = 10 \text{ ms}$)	$\lambda_{centroid}$	850	nm
Spectral bandwidth at 50% of I_{max} ($I_F = 1 \text{ A}, t_p = 10 \text{ ms}$)	Δλ	30	nm
Half angle	φ	± 60	0
Dimensions of active chip area	LxW	1 x 1	mm x mm
Rise and fall times of I _e (10% and 90% of I _{e max}) (I _F = 5 A, R _L = 50 Ω)	t _r / t _f	7 / 14	ns
Forward voltage ($I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$)	V _F	1.5 (≤ 1.8)	V
Forward voltage ($I_F = 5 \text{ A}, t_p = 100 \ \mu \text{s}$)	V _F	2 (≤ 2.9)	V
Radiant intensity ($I_F = 1 \text{ A}, t_p = 100 \ \mu s$)	I _{e, typ}	180	mW/sr
Temperature coefficient of I_e or Φ_e ($I_F = 1 \text{ A}, t_p = 10 \text{ ms}$)	TCI	-0.3	% / K
Temperature coefficient of V_F (I _F = 1 A, t _p = 10 ms)	TC _v	-1	mV / K
Temperature coefficient of wavelength $(I_F = 1 \text{ A}, t_p = 10 \text{ ms})$	$TC_{\lambda,}$ centroid	0.3	nm / K



Grouping	(T _A = 25 °C)
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Group	Min Total Radiant Flux	Max Total Radiant Flux	
	I _F = 1A, t _p = 10 ms	I _F = 1A, t _p = 10 ms	
	Φ _{e min} [mW]	Φ _{e max} [mW]	
SFH4232 - CB	320	500	
SFH4232 - DA	400	630	
SFH4232 - DB	500	800	

Note: Measured with integrating sphere.

Only one group in one package unit (variation lower 1.6:1)



 $I_{rel} = f(\lambda), T_A = 25^{\circ}C$



Relative Total Radiant Flux ^{1) page 12}

 Φ_e/Φ_e (1A) = f(I_F), T_A = 25°C, Single pulse, t_p= 100µs





Max. Permissible Forward Current



Permissible Pulse Handling Capability

 $I_F = f(t_p), T_S = 85 \text{ °C}, \text{ duty cycle } D = \text{parameter}$ OHF04177 5.5 А I_{F} 1 4.5 D 4.0 0.005 3.5 0.01 0.02 3.0 0.05 0.1 2.5 0.2 0.33 2.0 0.5 1 1.5 1.0 0.5 0 10^{-5} 10^{-4} 10^{-3} 10^{-2} 10^{-1} 10^{0} 10^{1} s 10^{2} - *t*p

Forward Current ^{1) page 12}







Radiation Characteristics ^{1) page 12}

 $I_{rel} = f(\phi), T_A = 25^{\circ}C$



Package Outline



Dimensions in mm (inch). Cathode mark on the bottom side



C67062-A0007-A2-02



Note:

Corrosion robustness better than EN 60068-2-60 (method 4): with enhanced corrosion test: 40°C / 90%rh / 15ppm H2S / 336h

Type:

SFH 4232

Package

Platinum Dragon

Approximate Weight:

0.2 g

Recommended Solder Pad



Dimensions in mm (inch).

Attention

Anode and Heatsink are electrically connected

OHAY0681



Reflow Soldering Profile

Product complies to MSL Level 2 acc. to JEDEC J-STD-020D.01



					OHA04612
Profile Feature	Symbol Symbol	Pb-Free (SnAgCu) Assembly			Unit
Profil-Charakteristik		Minimum	Recommendation	Maximum	Einheit
Ramp-up rate to preheat ^{*)} 25 °C to 150 °C			2	3	K/s
Time t _s T _{Smin} to T _{Smax}	t _s	60	100	120	S
Ramp-up rate to peak* ⁾ T _{Smax} to T _P			2	3	K/s
Liquidus temperature	TL		217		°C
Time above liquidus temperature	tL		80	100	s
Peak temperature	T _P		245	260	°C
Time within 5 °C of the specified peak temperature T_P - 5 K	t _P	10	20	30	S
Ramp-down rate* T _P to 100 °C			3	6	K/s
Time 25 °C to T _P				480	S

All temperatures refer to the center of the package, measured on the top of the component

* slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range



Taping



Dimensions in mm (inch).

Tape and Reel

24 mm tape with 800 pcs. on \varnothing 180 mm reel





Tape dimensions [mm]

W	Po	P ₁	P ₂	D ₀	E	F
24 + 0.3 / - 0.1	4 ± 0.1	8 ± 0.1 or 12 ± 0.1	2 ± 0.1	1.5 ± 0.1	1.75 ± 0.1	11.5 ± 0.05

Reel dimensions [mm]

Α	W	N _{min}	W ₁	W _{2max}
180	24	60 / 100	24.4 + 2	30.4

Barcode-Product-Label (BPL)



Dry Packing Process and Materials



Note:

Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card. Regarding dry pack you will find further information in the internet. Here you will also find the normative references like JEDEC.



Transportation Packing and Materials



Dimensions of transportation box in mm

Width	Length	Height
195 ± 5	195 ± 5	42 ± 5



Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the Internet.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Components used in life-support devices or systems must be expressly authorized for such purpose! Critical components* may only be used in life-support devices** or systems with the express written approval of OSRAM OS.

*) A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or the effectiveness of that device or system.

**) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.



Glossary

¹⁾ Typical Values: Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.



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